



### **40V N-Channel Enhancement Mode MOSFET**

Voltage

40 V

Current

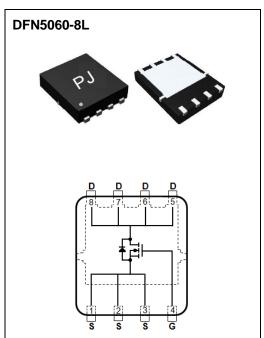
21A

#### **Features**

- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@12A<32m\Omega$
- R<sub>DS(ON)</sub>, V<sub>GS</sub>@4.5V, I<sub>D</sub>@10A<40mΩ
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance.
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case: DFN5060-8L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0028 ounces, 0.08 grams



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	40	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20		
Continuous Drain Current	T <sub>C</sub> =25°C	I <sub>D</sub>	21	А	
	T <sub>C</sub> =100°C		13.2		
Pulsed Drain Current <sup>(Note 1)</sup>	T <sub>C</sub> =25°C	I <sub>DM</sub>	80		
Power Dissipation	T <sub>C</sub> =25°C	Po	25	W	
	T <sub>C</sub> =100°C		10		
Continuous Drain Current	T <sub>A</sub> =25°C	I <sub>D</sub>	5.9	А	
	T <sub>A</sub> =70°C		4.7		
Power Dissipation	T <sub>A</sub> =25°C	D-	2.0	W	
Power Dissipation	T <sub>A</sub> =70°C	Po	1.3		
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C	
Typical Thermal Resistance <sup>(Note 4,5)</sup>	Junction to Case	$R_{ heta JC}$	5.0	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

• Limited only By Maximum Junction Temperature





## **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	40	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	1.2	1.8	2.5			
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =12A	-	26	32	mΩ		
		$V_{GS}$ =4.5V, $I_{D}$ =10A	-	32	40			
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =40V, $V_{GS}$ =0V	-	-	1.0	uA		
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA		
Dynamic (Note 6)								
Total Gate Charge	$Q_g$	V <sub>DS</sub> =20V, I <sub>D</sub> =5A, V <sub>GS</sub> =4.5V <sup>(Note 3)</sup>	-	4.4	-	nC		
Gate-Source Charge	$Q_gs$		-	1.3	-			
Gate-Drain Charge	$Q_gd$	V <sub>GS</sub> =4.5V	-	1.7	-			
Input Capacitance	Ciss	\\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	-	425	-	pF		
Output Capacitance	Coss	$V_{DS}$ =25V, $V_{GS}$ =0V, f=1.0MHZ	-	48	-			
Reverse Transfer Capacitance	Crss	I=I.UIVIMZ	-	36	-			
Turn-On Delay Time	td <sub>(on)</sub>		-	9.4	-			
Turn-On Rise Time	t <sub>r</sub>	V <sub>DD</sub> =20V, I <sub>D</sub> =1A,	-	29	-	ns		
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}$ =4.5V, $R_{G}$ =25 $\Omega$	-	21	-			
Turn-Off Fall Time	t <sub>f</sub>		-	29	-			
Drain-Source Diode								
Maximum Continuous Drain-Source	ı		-	-	21	А		
Diode Forward Current	I <sub>S</sub>							
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.74	1	V		

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial  $T_J$  =25°C.
- 4. The maximum current rating is package limited.
- 5. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





#### TYPICAL CHARACTERISTIC CURVES

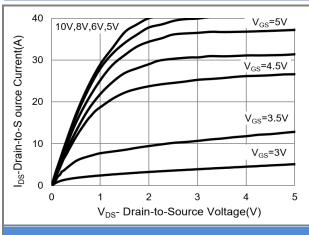
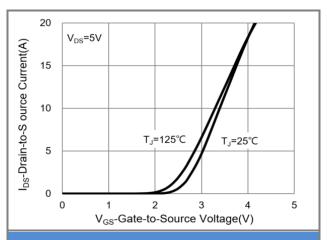


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

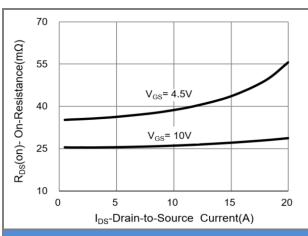


Fig.3 On-Resistance vs. Drain Current

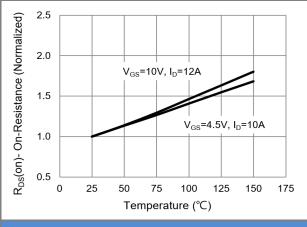


Fig.4 On-Resistance vs. Junction temperature

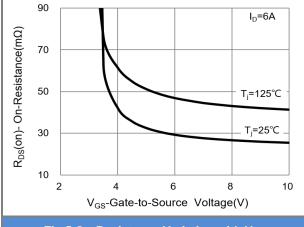
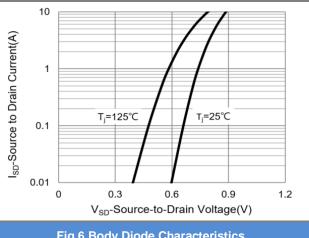


Fig.5 On-Resistance Variation with V<sub>GS</sub>



**Fig.6 Body Diode Characteristics** 





#### **TYPICAL CHARACTERISTIC CURVES**

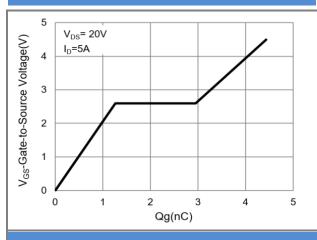


Fig.7 Gate-Charge Characteristics

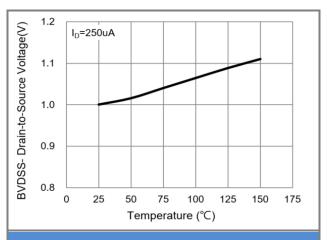


Fig.8 Breakdown Voltage Variation vs. Temperature

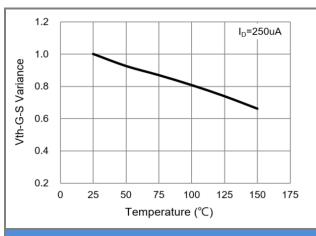


Fig.9 Threshold Voltage Variation with Temperature

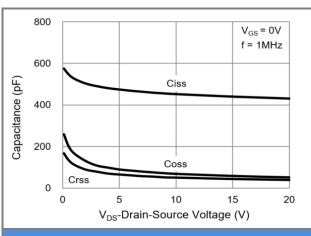


Fig.10 Capacitance vs. Drain-Source Voltage

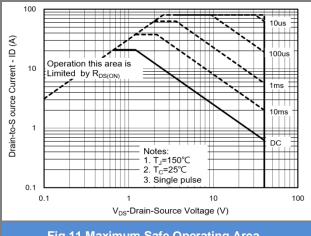


Fig.11 Maximum Safe Operating Area

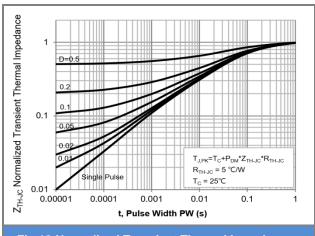


Fig.12 Normalized Transient Thermal Impedance

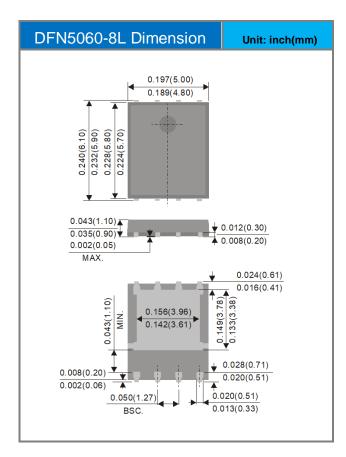


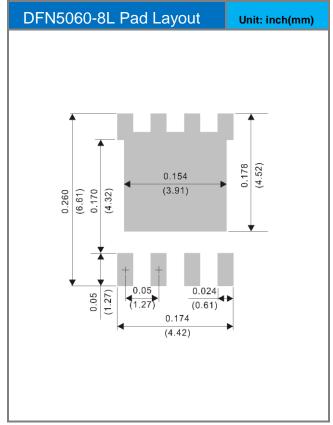


### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version	
PJQ5450_R2_00001	DFN5060-8L	3000pcs / 13" reel	Q5450	Halogen free	

### **Packaging Information & Mounting Pad Layout**









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